

REMARKS

The Office Action of March 12, 2004 was received and carefully reviewed. Reconsideration and withdrawal of the currently pending rejections are requested for the reasons advanced in detail below.

Claims 1-37 were pending prior to this instant Amendment, with claims 15-28 and 30-37 withdrawn from consideration. By this Amendment, claims 1-37 are canceled without prejudice to file a divisional application directed thereto, and new claims 38-57 are added to clearly define Applicant's invention over the cited art of record. Applicants believe that the new claims will be more easily reviewed by the Examiner, than amended claims. Consequently, claims 38-57 are currently pending in the instant application.

Claims 1, 4, 6, 9, 11 and 29 are rejected under 35 U.S.C. 103(a) over U.S. Patent no. 5,274,279 (Misawa et al.), in view of Applicant's admitted prior art (APA) and further in view of JP63-4624 (Hamazaki et al.), and claims 5, 10 and 14 are rejected under 35 U.S.C. 103(a) over these references, further in view of JP60-187030. These rejections are traversed for the reasons advanced below.

Initially, it does not appear that claims 2, 7 and 12 are officially included in a rejection, but are referred to as rejected on page 5 of the Office Action. Despite this issue, these claims are canceled herein rendering this aspect of the Office Action moot.

The presently claimed invention is directed to a method for manufacturing a semiconductor device including the steps of:

- forming a semiconductor film over a substrate;

- forming a wiring electrically connected to the semiconductor film; and

- forming a pixel electrode electrically connected to the wiring.

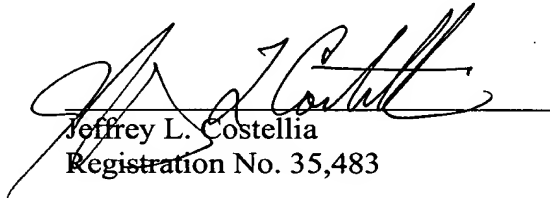
Specifically, the formed wiring includes a first layer including chromium and a second layer including aluminum. The first layer and the second layer are continuously formed by sputtering. Further, the first layer is formed in contact with the semiconductor film, and the pixel electrode is formed in contact with the first layer.

In response to the Office Action, new claims 38-57 are added to more clearly recite Applicants' invention which specifically recite forming a first layer comprising chromium and a second layer comprising aluminum continuously, as noted above. Support for this aspect of the invention is provided, at least, on page 20, last paragraph. Applicants contend

that this feature of the invention is not disclosed nor suggested by the cited art of record. As a result, consideration and allowance of the instant application are now appropriate.

In view of the foregoing, it is respectfully requested that the rejections of record be reconsidered and withdrawn, that claims 38-57 be allowed, and that the application be passed to issue. If a conference would be beneficial in expediting prosecution of the instant application, the Examiner is invited to telephone the undersigned to arrange such a conference.

Respectfully submitted,



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